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First Named Inventor	Wang Zhongze	INFORMATION DISCLOSURE STATEMENT FORM PTO-1449
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Examiner Signature	<i>Pham Thanh</i>	Date Considered	12/15/2005
*Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.			

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